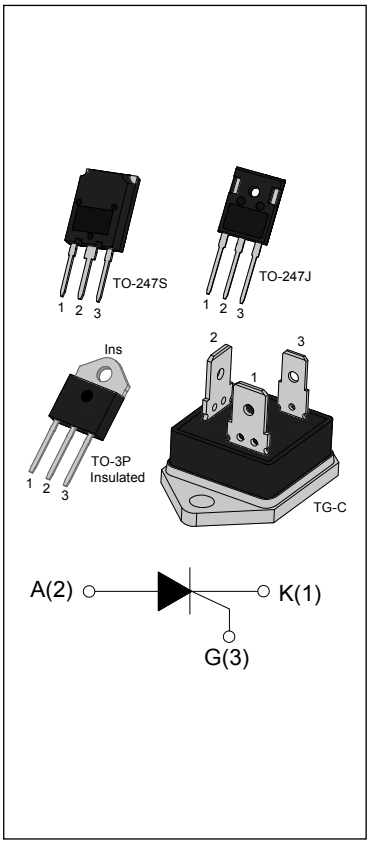
JCTxx55 Series 55A SCRs

Rev.9.0

DESCRIPTION:

With high ability to withstand the shock loading of large current, JCTxx55 SCRs provide high dv/dt rate with strong resistance to electromagnetic interference. They are especially recommended for use on solid state relay, motorcycle, power charger, T-tools etc.

From all three terminals to external heatsink, JCTxx55Z provides a rated insulation voltage of 2500 V_{RMS}, complying with UL standards (File ref: E252906).



MAIN FEATURES

Symbol	Value	Symbol
V_{DRM}/ V_{RRM}	1000/1200	V
$I_{T(RMS)}$	55	A
I_{GT}	≤50	mA

ABSOLUTE MAXIMUM RATINGS

Parameter		Symbol	Value	Unit
Storage junction temperature range		T_{stg}	-40-150	℃
Operating junction temperature range		T_j	-40-125	℃
Repetitive peak off-state voltage(T_j=25℃)		V_{DRM}	1000/1200	V
Repetitive peak reverse voltage(T_j=25℃)		V_{RRM}	1000/1200	V
Non repetitive peak off-state voltage		V_{DSM}	V_{DRM} +100	V
Non repetitive peak reverse voltage		V_{RSM}	V_{RRM} +100	V
RMS on-state current	TO-3P Ins (T_C=70℃)	$I_{T(RMS)}$	55	A
	TO-247S /TO-247J (T_C=75℃)			
	TG-C (T_C=73℃)			

Non repetitive surge peak on-state current (tp=10ms)	I_{TSM}	520	A
I^2t value for fusing (tp=10ms)	I^2t	1350	A^2s
Critical rate of rise of on-state current (I_G=2×I_{GT})	dI/dt	150	A/μs
Peak gate current	I_{GM}	5	A
Average gate power dissipation	$P_{G(AV)}$	1	W
Peak gate power	P_{GM}	10	W

ELECTRICAL CHARACTERISTICS (T_j=25℃ unless otherwise specified)

Symbol	Test Condition	Value			Unit
		MIN.	TYP.	MAX.	
I_{GT}	V_D=12V R_L=33Ω	-	-	50	mA
V_{GT}		-	-	1.5	V
V_{GD}	V_D=V_{DRM} T_j=125℃ R_L=3.3KΩ	0.2	-	-	V
I_L	I_G=1.2I_{GT}	-	-	150	mA
I_H	I_T=500mA	-	-	120	mA
dV/dt	V_D=2/3V_{DRM} Gate Open T_j=125℃	800	-	-	V/μs

STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX)	Unit
V_{TM}	I_{TM}=80A tp=380μs	T_j=25℃	1.6	V
I_{DRM}	V_D=V_{DRM} V_R=V_{RRM}	T_j=25℃	10	μA
I_{RRM}		T_j=125℃	6	mA

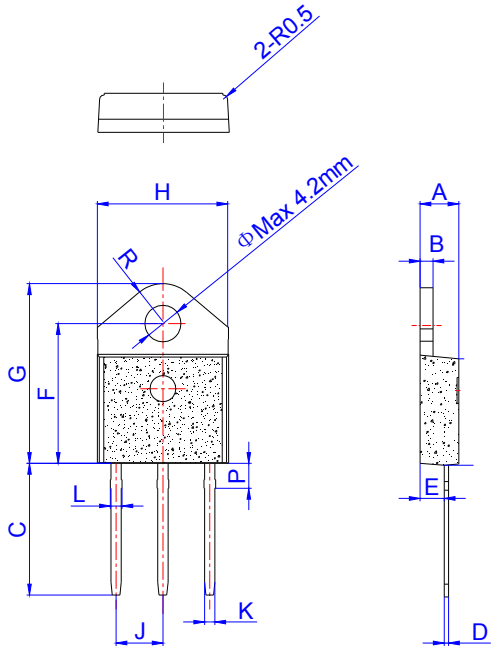
THERMAL RESISTANCES

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	junction to case(AC)	TO-3P Ins	0.65	℃/W
		TO-247S/TO-247J	0.6	
		TG-C	0.63	

ORDERING INFORMATION

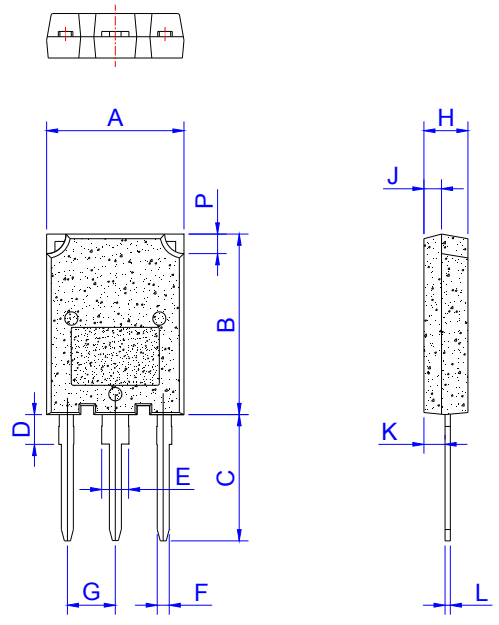
J	CT	12	55	Z
JieJie Microelectronics Co.,Ltd	SCRs	10:V_{DRM} /V_{RRM} ≥1000V 12:V_{DRM} /V_{RRM} ≥1200V	$I_{T(RMS)}$:55A	Z:TO-3P Ins T:TG-C CS:TO-247S SJ:TO-247J

PACKAGE MECHANICAL DATA



TO-3P Ins

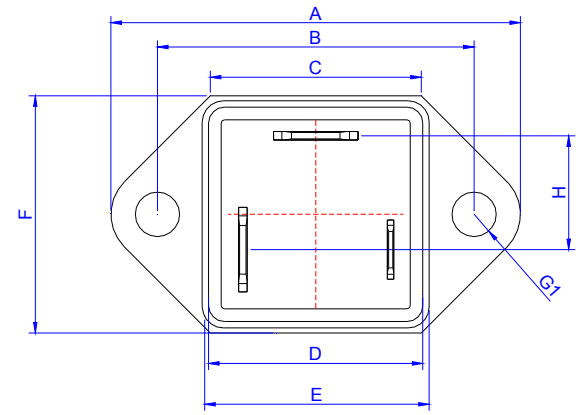
Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	1.45		1.55	0.057		0.061
C	14.35		15.60	0.565		0.614
D	0.50		0.70	0.020		0.028
E	2.70		2.90	0.106		0.114
F	15.80		16.50	0.622		0.650
G	20.40		21.10	0.803		0.831
H	15.10		15.50	0.594		0.610
J	5.40		5.65	0.213		0.222
K	1.10		1.40	0.043		0.055
L	1.35		1.50	0.053		0.059
P	2.80		3.00	0.110		0.118
R		4.35			0.171	

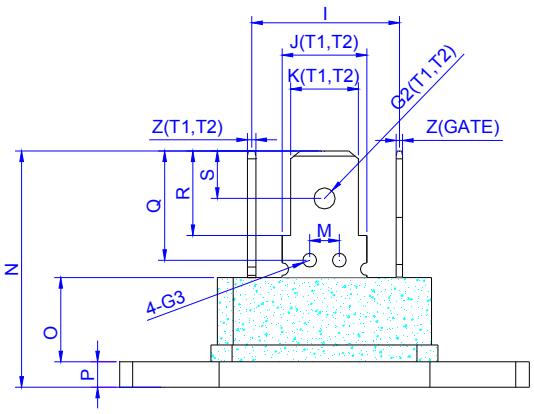


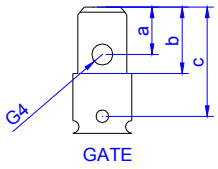
TO-247S

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.1		16.1	0.594		0.634
B	19.8		20.8	0.78		0.819
C	13.8		14.8	0.543		0.583
D	3.00		4.00	0.118		0.157
E	2.75		3.35	0.108		0.132
F	1.30		1.50	0.051		0.059
G	5.10		5.80	0.201		0.228
H	4.50		5.50	0.177		0.217
J	1.45		2.15	0.057		0.085
K	1.90		2.80	0.075		0.110
L	0.55		0.80	0.022		0.031
P	2.00		2.40	0.079		0.094

PACKAGE MECHANICAL DATA



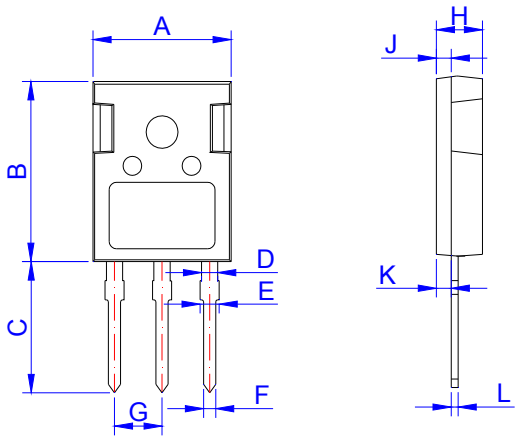




TG-C

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			39.2			1.543
B	29.8	30.0	30.2	1.173	1.181	1.189
C			20.2			0.795
D			20.5			0.807
E			21.6			0.85
F			23			0.905
G1	Φ4.1	Φ4.2	Φ4.3	Φ0.161	Φ0.165	Φ0.169
H		10.3			0.406	
I		13.9			0.547	
J(T1,T2)		8			0.315	
K(T1,T2)		6.4			0.252	
M	2.7	3.0	3.3	0.106	0.118	0.130
N			22.8			0.898
O		8.2			0.323	
P		2.5			0.098	
Q	9.45	9.75	10.1	0.374	0.383	0.398
R	7.8	7.95	8.1	0.307	0.313	0.319
S	4.3	4.5	4.7	0.169	0.177	0.185
Z(T1,T2)	0.78	0.8	0.85	0.0307	0.0315	0.0335
G2(T1,T2)		Φ2	Φ2.2		Φ0.079	Φ0.087
G3	Φ1.1	Φ1.3	Φ1.5	Φ0.043	Φ0.051	Φ0.059
G4		Φ1.55	Φ1.75		Φ0.061	Φ0.069
a	2.95	3.15	3.35	0.116	0.124	0.132
b	6.2	6.35	6.5	0.244	0.25	0.256
c	9.35	9.75	10	0.368	0.384	0.393
Z(GATE)	0.58	0.6	0.65	0.0228	0.0236	0.0256
J(GATE)		5.6			0.221	
K(GATE)		4.65			0.183	

PACKAGE MECHANICAL DATA



TO-247J

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.50	15.80	16.10	0.610	0.622	0.634
B	20.80	21.00	22.20	0.819	0.828	0.874
C	19.70	20.00	20.30	0.776	0.787	0.799
D	1.80	2.00	2.20	0.071	0.079	0.087
E	1.90	2.10	2.30	0.075	0.083	0.091
F	1.00	1.20	1.40	0.039	0.047	0.055
G		5.44			0.214	
H	4.80	5.00	5.20	0.189	0.197	0.205
J	1.90	2.00	2.10	0.075	0.079	0.083
K	2.20	2.35	2.50	0.087	0.093	0.098
L	0.41	0.60	0.79	0.016	0.024	0.031

PACKAGE INFORMATION

PACKAGE	OUTLINE	TUBE (PCS)	INNER BOX (PCS)	PER CARTON
TO-3P	TUBE	30	450	3,600
TO-247S	TUBE	30	450	3,600
TO-247J	TUBE	30	450	3,600
PACKAGE	**WEIGHT (PER PCS)**	**OUTLINE**	**INNER BOX (PCS)**	**PER CARTON (PCS)**
TG-C	21.5g	BOX	80	720

FIG.1: Maximum power dissipation versus RMS on-state current

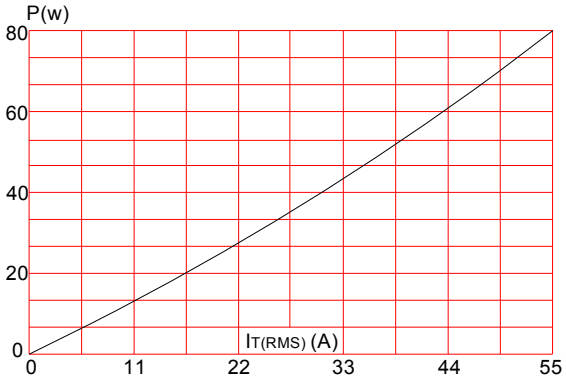


FIG.2: RMS on-state current versus case temperature

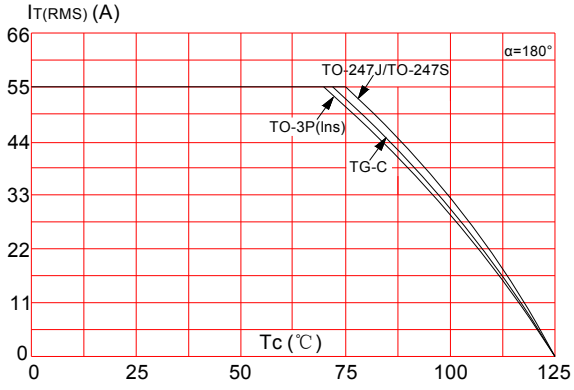


FIG.3: Surge peak on-state current versus number of cycles

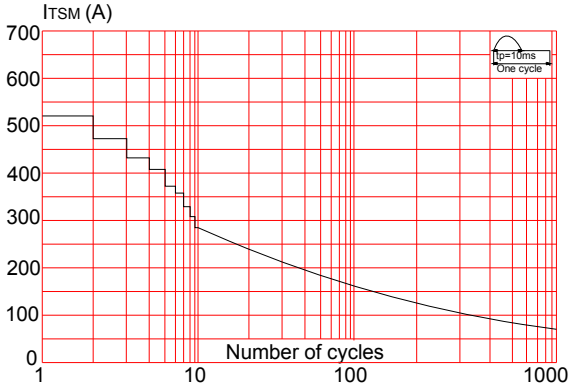


FIG.4: On-state characteristics (maximum values)

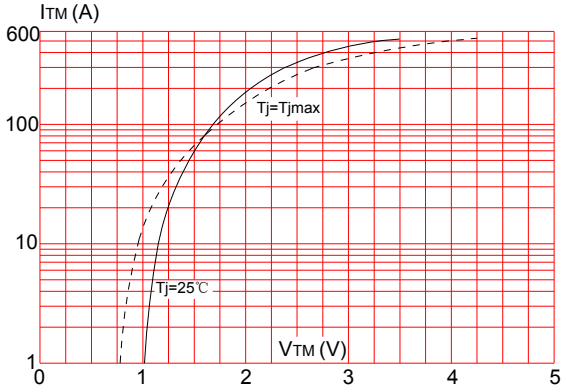


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width tp<10ms, and corresponging value of I^2t (dI/dt < 150A/μs)

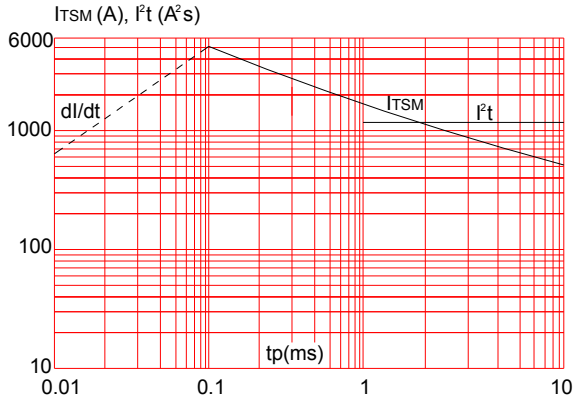
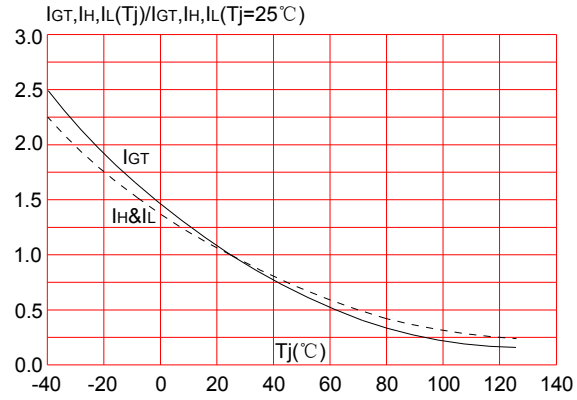


FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature



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